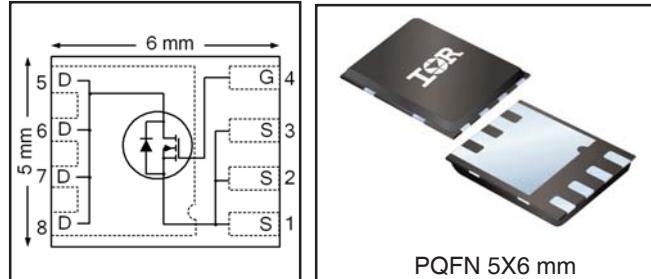


### HEXFET® Power MOSFET

<b>V<sub>DS</sub></b>	<b>200</b>	<b>V</b>
<b>R<sub>DS(on)</sub> max</b> (@V <sub>GS</sub> = 10V)	<b>55</b>	<b>mΩ</b>
<b>Q<sub>g</sub> (typical)</b>	<b>36</b>	<b>nC</b>
<b>R<sub>G</sub> (typical)</b>	<b>1.9</b>	<b>Ω</b>
<b>I<sub>D</sub></b> (@T <sub>c(Bottom)</sub> = 25°C)	<b>34</b>	<b>A</b>



### Applications

- Secondary Side Synchronous Rectification
- Inverters for DC Motors
- DC-DC Brick Applications
- Boost Converters

### Features and Benefits

#### Features

Low R <sub>DS(on)</sub>
Low Thermal Resistance to PCB ( $\leq 0.8^{\circ}\text{C}/\text{W}$ )
100% R <sub>g</sub> tested
Low Profile ( $\leq 0.9$ mm)
Industry-Standard Pinout
Compatible with Existing Surface Mount Techniques
RoHS Compliant Containing no Lead, no Bromide and no Halogen
MSL1, Industrial Qualification

#### Benefits

Lower Conduction Losses
Enable better thermal dissipation
Increased Reliability
Increased Power Density
Multi-Vendor Compatibility
Easier Manufacturing
Environmentally Friendlier
Increased Reliability

results in  
→

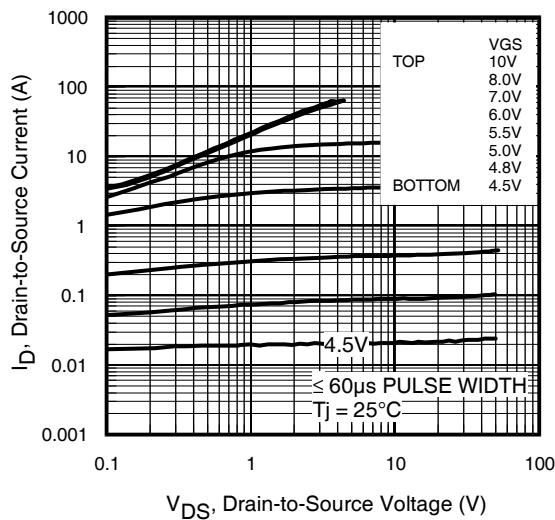
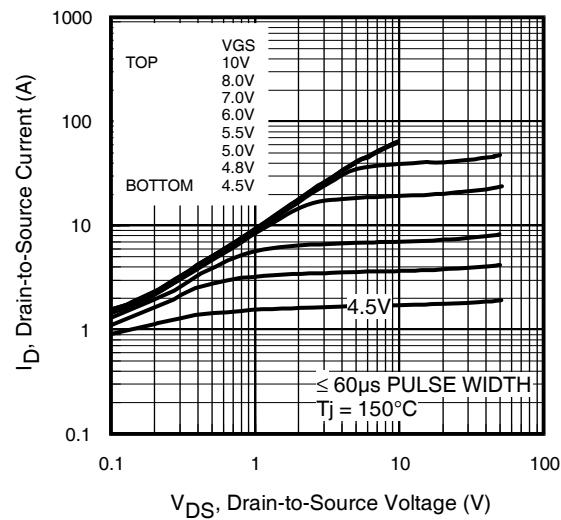
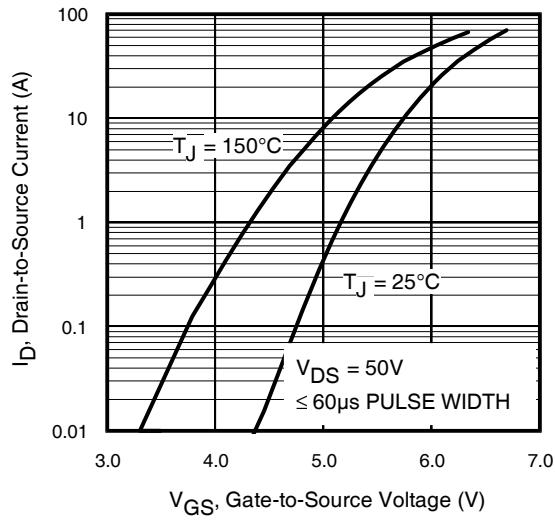
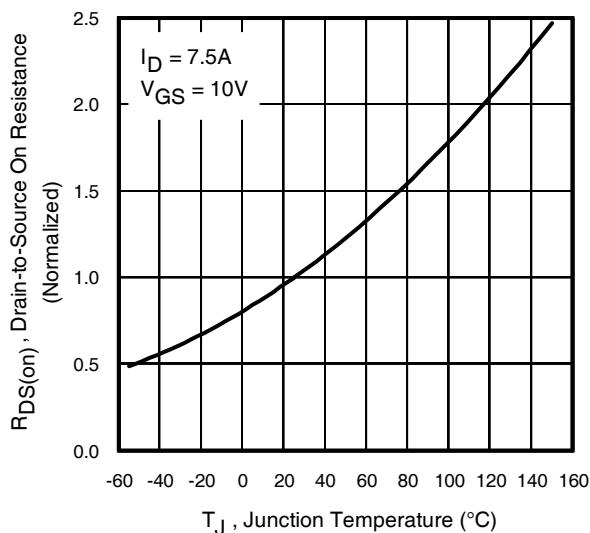
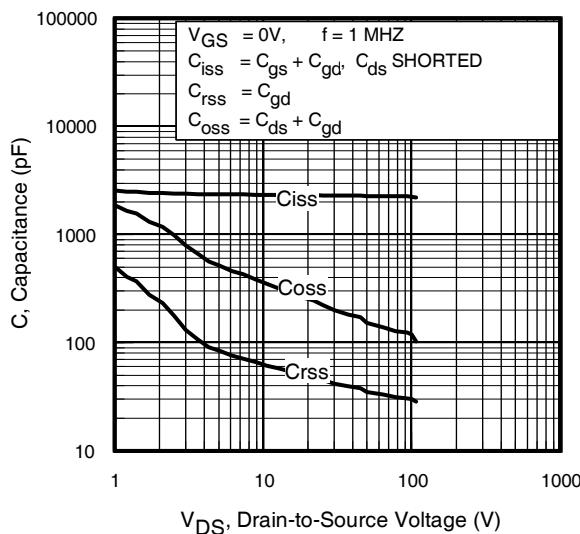
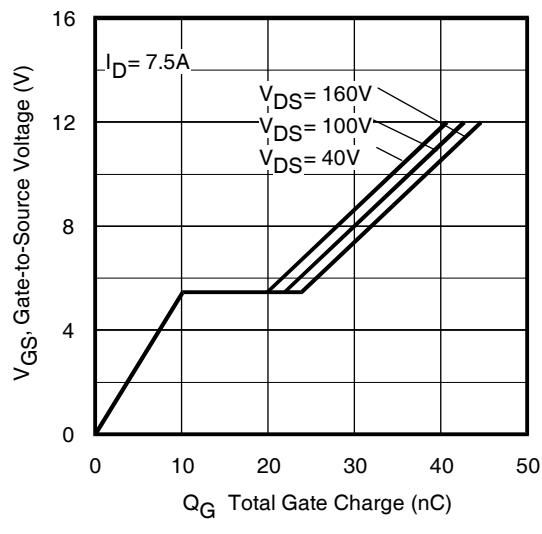
Orderable part number	Package Type	Standard Pack		Note
		Form	Quantity	
IRFH5020TRPbF	PQFN 5mm x 6mm	Tape and Reel	4000	
IRFH5020TR2PbF	PQFN 5mm x 6mm	Tape and Reel	400	EOL notice #259

### Absolute Maximum Ratings

	Parameter	Max.	Units
V <sub>DS</sub>	Drain-to-Source Voltage	200	V
V <sub>GS</sub>	Gate-to-Source Voltage	± 20	
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	5.1	
I <sub>D</sub> @ T <sub>A</sub> = 70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	4.1	
I <sub>D</sub> @ T <sub>C(Bottom)</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	34	
I <sub>D</sub> @ T <sub>C(Bottom)</sub> = 100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	21	A
I <sub>D</sub> @ T <sub>C(Top)</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	7.8	
I <sub>D</sub> @ T <sub>C(Top)</sub> = 100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	4.9	
I <sub>DM</sub>	Pulsed Drain Current ①	63	
P <sub>D</sub> @ T <sub>A</sub> = 25°C	Power Dissipation ⑤	3.6	W
P <sub>D</sub> @ T <sub>C(Top)</sub> = 25°C	Power Dissipation ④	8.3	
	Linear Derating Factor ④	0.07	W/°C
T <sub>J</sub>	Operating Junction and	-55 to + 150	°C
T <sub>STG</sub>	Storage Temperature Range		

Notes ① through ⑤ are on page 9



**Fig 1.** Typical Output Characteristics**Fig 2.** Typical Output Characteristics**Fig 3.** Typical Transfer Characteristics**Fig 4.** Normalized On-Resistance Vs. Temperature**Fig 5.** Typical Capacitance Vs.Drain-to-Source Voltage**Fig 6.** Typical Gate Charge Vs.Gate-to-Source Voltage

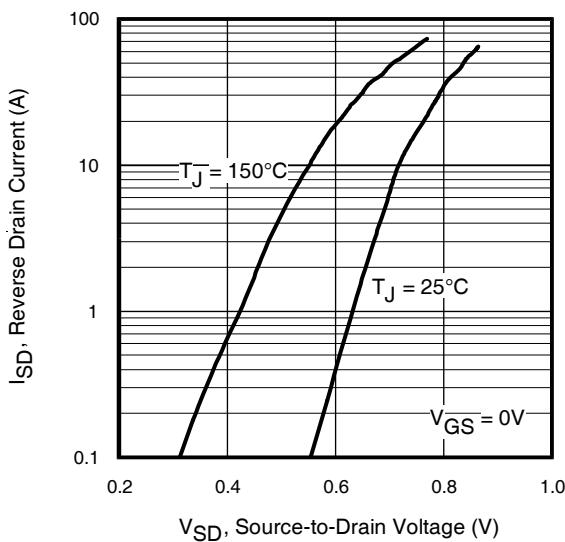


Fig 7. Typical Source-Drain Diode Forward Voltage

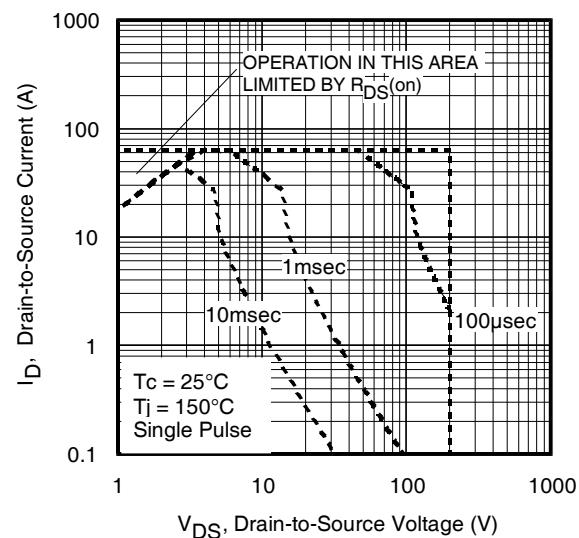


Fig 8. Maximum Safe Operating Area

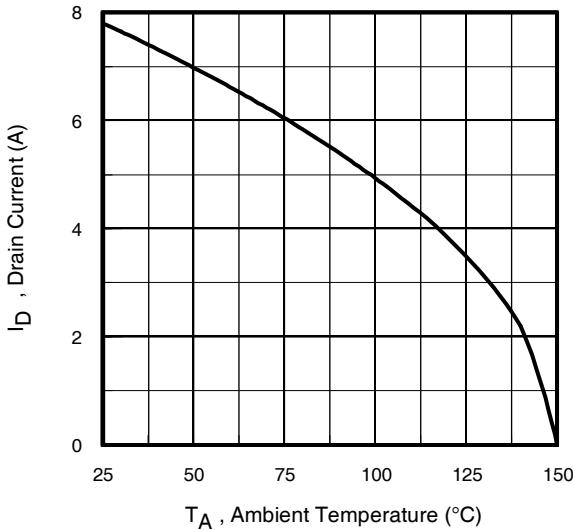


Fig 9. Maximum Drain Current Vs. Case (Top) Temperature

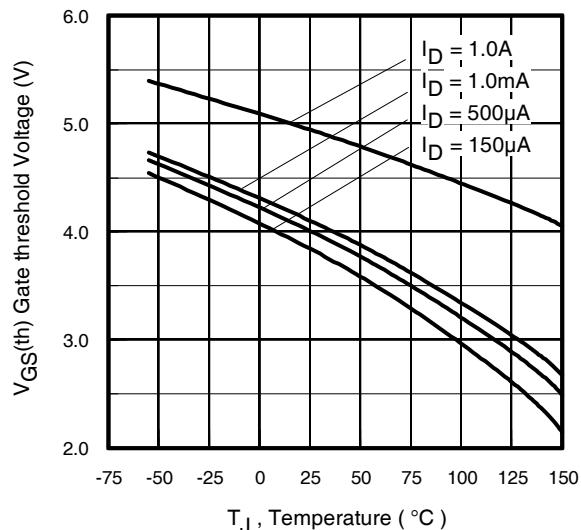


Fig 10. Threshold Voltage Vs. Temperature

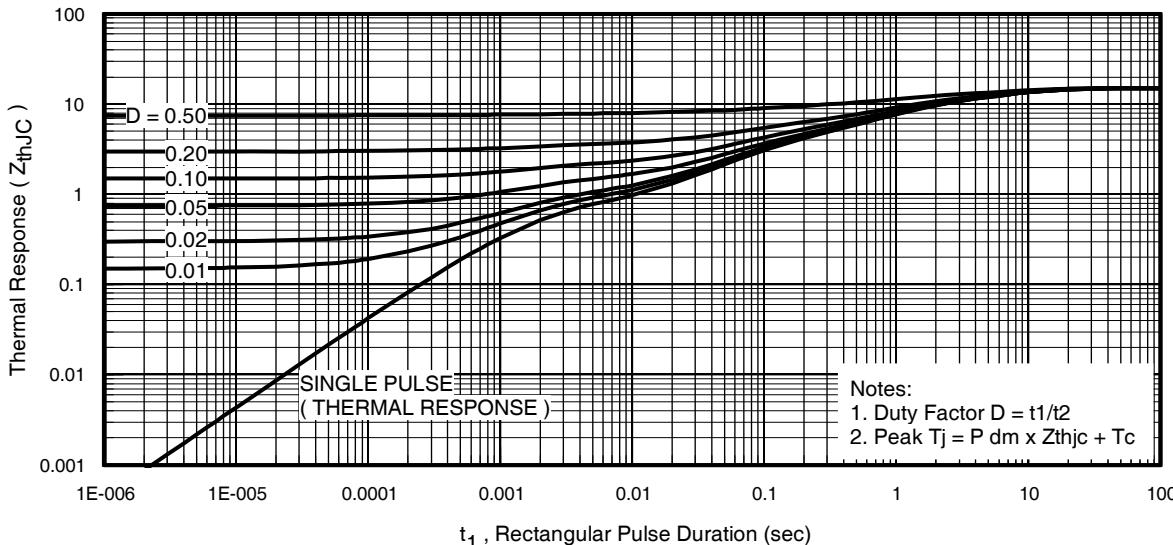
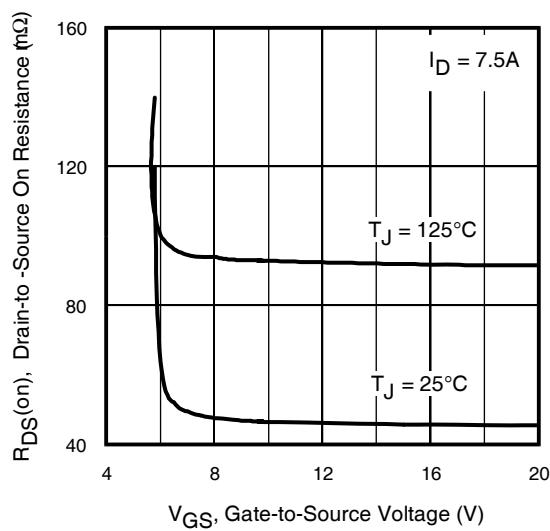
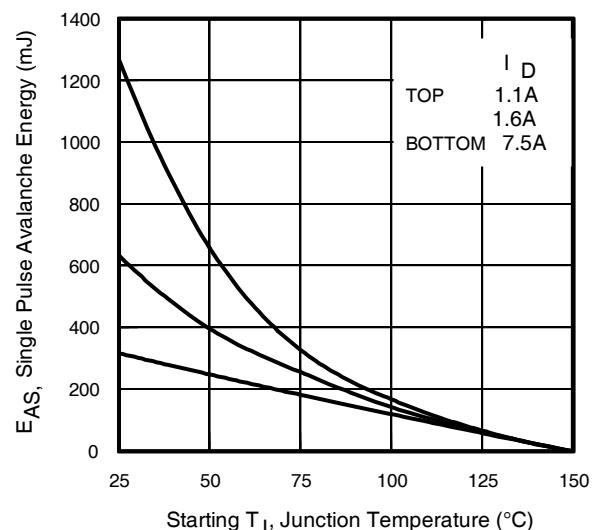
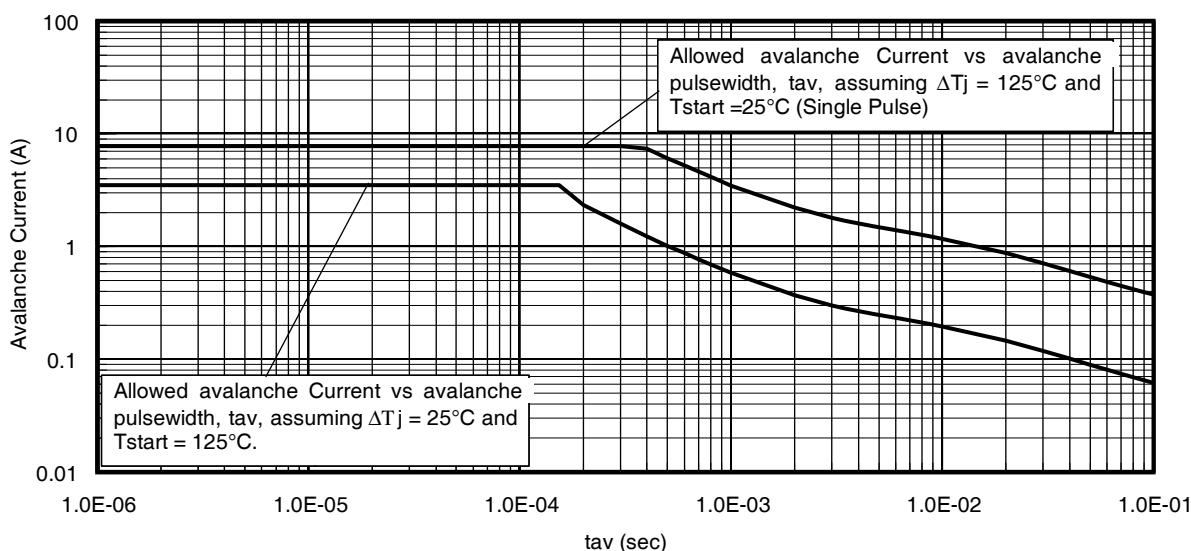
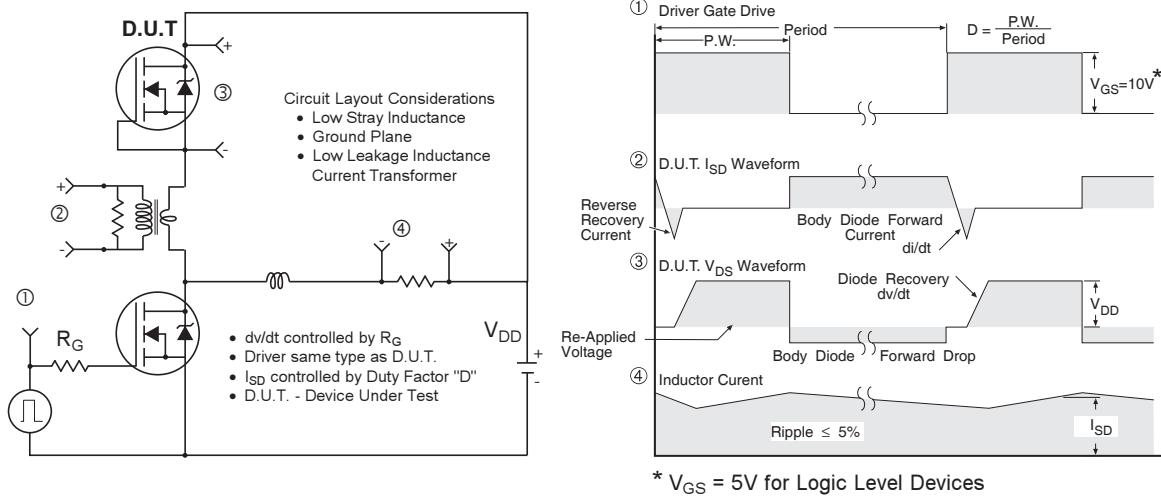
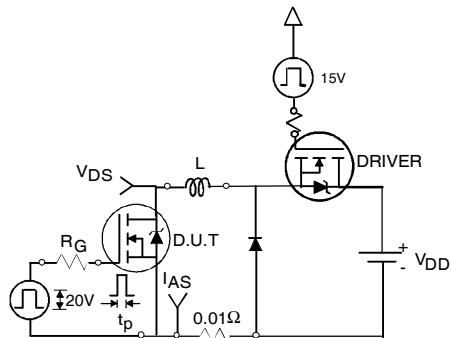


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case (Top)

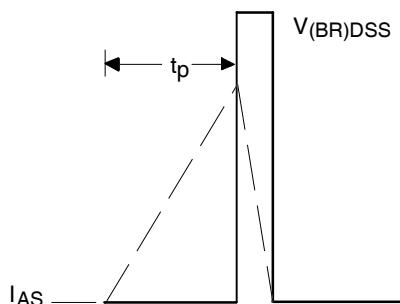
**Fig 12.** On-Resistance vs. Gate Voltage**Fig 13.** Maximum Avalanche Energy vs. Drain Current**Fig 14.** Typical Avalanche Current vs. Pulsewidth



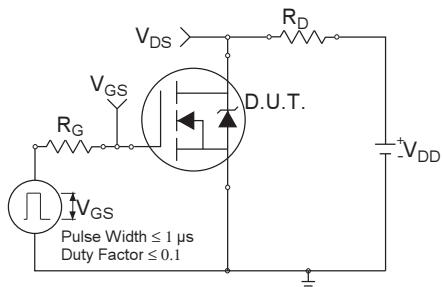
**Fig 15.** Peak Diode Recovery  $dv/dt$  Test Circuit for N-Channel HEXFET® Power MOSFETs



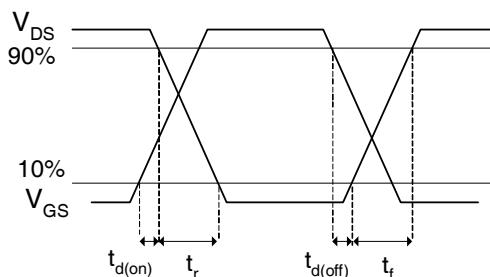
**Fig 16a.** Unclamped Inductive Test Circuit



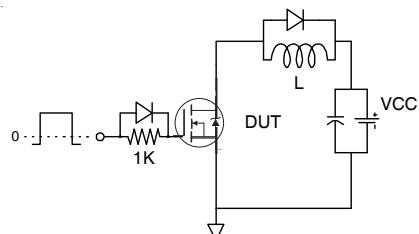
**Fig 16b.** Unclamped Inductive Waveforms



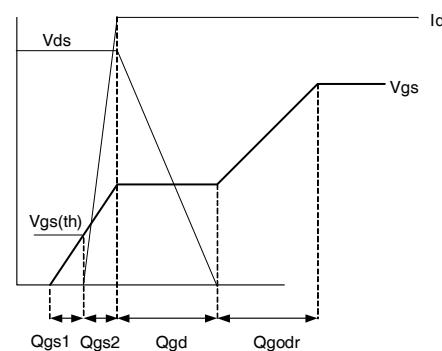
**Fig 17a.** Switching Time Test Circuit



**Fig 17b.** Switching Time Waveforms



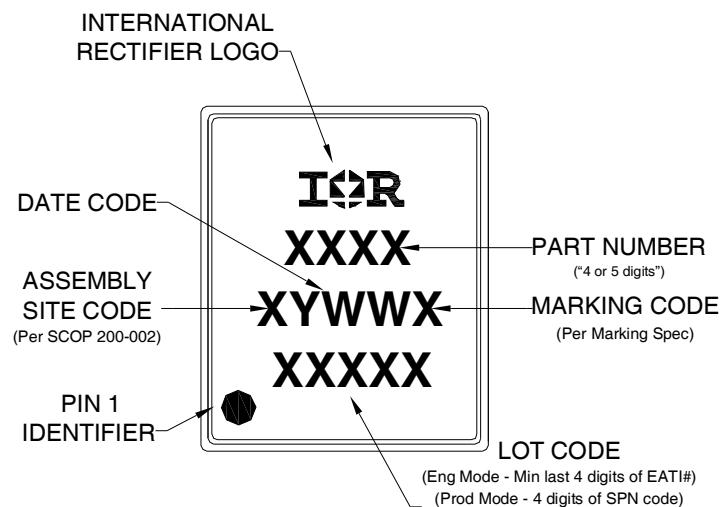
**Fig 18a.** Gate Charge Test Circuit



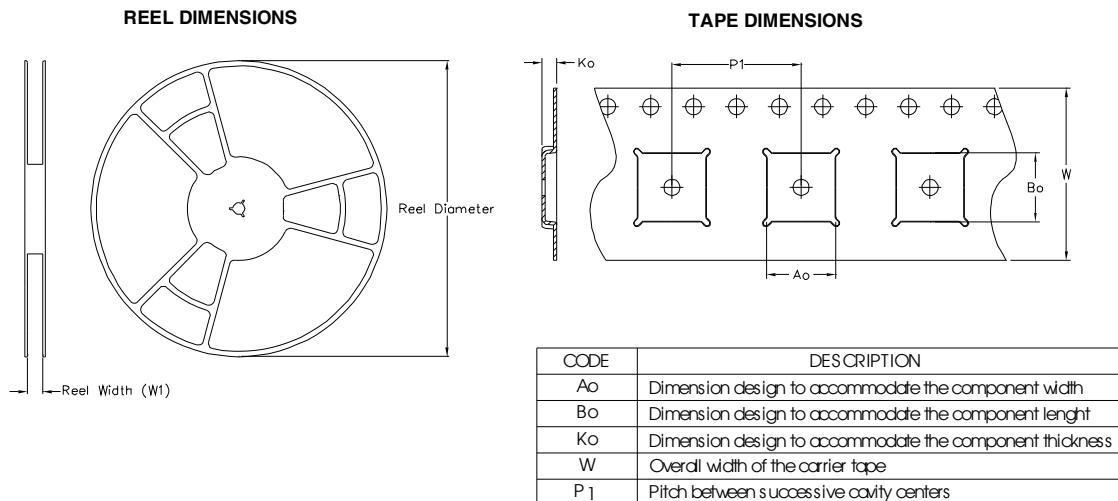
**Fig 18b.** Gate Charge Waveform



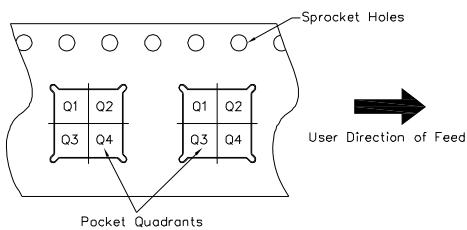
## PQFN 5x6 Part Marking



## PQFN 5x6 Tape and Reel



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Note: All dimension are nominal

Package Type	Reel Diameter (Inch)	QTY	Reel Width W1 (mm)	Ao (mm)	Bo (mm)	Ko (mm)	P1 (mm)	W (mm)	Pin 1 Quadrant
5 X 6 PQFN	13	4000	12.4	6.300	5.300	1.20	8.00	12	Q1

Note: For the most current drawing please refer to IR website at: <http://www.irf.com/package/>

**Qualification information<sup>†</sup>**

Qualification level	Industrial <sup>††</sup> (per JEDEC JESD47F <sup>†††</sup> guidelines )	
Moisture Sensitivity Level	PQFN 5mm x 6mm	MSL1 (per JEDEC J-STD-020D <sup>†††</sup> )
RoHS compliant	Yes	

<sup>†</sup> Qualification standards can be found at International Rectifier's web site  
<http://www.irf.com/product-info/reliability>

<sup>††</sup> Higher qualification ratings may be available should the user have such requirements.  
 Please contact your International Rectifier sales representative for further information:  
<http://www.irf.com/whoto-call/salesrep/>

<sup>†††</sup> Applicable version of JEDEC standard at the time of product release.

**Notes:**

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting  $T_J = 25^\circ\text{C}$ ,  $L = 11.3\text{mH}$ ,  $R_G = 25\Omega$ ,  $I_{AS} = 7.5\text{A}$ .
- ③ Pulse width  $\leq 400\mu\text{s}$ ; duty cycle  $\leq 2\%$ .
- ④  $R_\theta$  is measured at  $T_J$  of approximately  $90^\circ\text{C}$ .
- ⑤ When mounted on 1 inch square 2 oz copper pad on 1.5x1.5 in. board of FR-4 material.

**Revision History**

Date	Comment
4/14/2014	<ul style="list-style-type: none"> <li>• Updated ordering information to reflect the End-Of-Life (EOL) of the mini-reel option (EOL notice #259) on page1</li> <li>• Corrected typo on Breakdown Voltage Temp. Coefficient from "0.02V/C" to "0.22V/C" on page 2.</li> <li>• Updated Package outline on page7.</li> <li>• Updated data sheet with the new IR corporate template.</li> </ul>
5/5/2014	<ul style="list-style-type: none"> <li>• Updated <math>\text{T}_{rr}</math> Typ/Max from "46/69ns" to "45/68ns" on page 2.</li> <li>• Updated <math>\text{Q}_{rr}</math> Typ/Max from "97/150nC" to "459/689nC" on page 2.</li> </ul>
4/28/2015	<ul style="list-style-type: none"> <li>• Updated package outline for "option B" and added package outline for "option G" on page 7</li> <li>• Updated tape and reel on page 8.</li> </ul>
5/19/2015	<ul style="list-style-type: none"> <li>• Updated package outline for "option G" on page 7.</li> <li>• Updated "IFX logo" on page 1 and page 9.</li> </ul>

International  
 Rectifier  
 AN INFINEON TECHNOLOGIES COMPANY

**IR WORLD HEADQUARTERS:** 101 N. Sepulveda Blvd., El Segundo, California 90245, USA  
 To contact International Rectifier, please visit <http://www.irf.com/whoto-call/>

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